FI566 Physics of Semiconductor Device

Module name:	Physics of Semiconductor Device						
Module level, if applicable:	Undergraduate						
Code:	FI566						
Sub-heading, if applicable:	-						
Classes, if applicable:	-						
Semester:	6 th						
Module coordinator:	Andi Suhandi						
Lecturer(s):	Andi Suhandi						
Language:	Bahasa Ir	ndonesia					
Classification within the curriculum:	Optional course						
Type of Teaching	Contact	hours per week during the semester	Class Size				
Lecture (conceptual, contextual, and problem-solving approaches through expository, and discussions) Structured activities (assignments based on conceptual, contextual, and problem-solving approaches) Self-study (reading literature)		hours 30 minutes	20				
Workload:	Total workload is 136 hours 4.8 ECTS (8.160 minutes) per semester which consists of 2100 minutes (1.22 ECTS) lectures, 2520 minutes (1.58 ECTS) structured activities, 2520 minutes (1.58 ECTS) self-study per week for 14 weeks, 400 minutes (0.2 ECTS) for each exam, and 480 (0.22 ECTS) minutes for each exam preparation.						
Credit points:	4.8 ECTS						
Pre-requisites course(s):	Basic Physics 1 & 2, Material Physics						
Course Learning Outcomes (CLO):	After takin CLO1. CLO2. CLO3. CLO4. CLO5. CLO6. CLO7.	devices and optoelectronic devices) and their different electronic systems/devices. Apply concepts, laws, principles, and principles of physics to semiconductor materials and devices Explain the basic structure of semiconductor devices (electronic and optoelectronic devices). Explain the structure and physical mechanism of operation of various electronic devices. Explain the structure and physical mechanism of operation of various optoelectronic devices. Explain the characteristics of various electronic devices.					

	CLO8. Apply various electronic and optoelectronic devices electronic systems/devices that are widely used everyday life. CLO9. Explain the process of characterizing the phys properties of various electronic and optoelectrodevices.						
	CLO10. Analyze of physical properties of various electronic and optoelectronic devices based on the data from the characterization of different electronic and optoelectronic devices						
Content:	Various semiconductor devices (electronic devices and optoelectronic devices) and their different electronic systems/devices. Concepts, laws, principles, and principles of physics to semiconductor materials and devices. The basic structure of semiconductor devices (electronic and optoelectronic devices). The system and the physical mechanism of operation of various electronic devices. The structure and the physical mechanism of operation of various optoelectronic devices. The characteristics of various electronic devices. Various optoelectronic devices. The characterizing the physical properties of various electronic and optoelectronic devices.						
	The final mark will be weight as follow:						
	No	CLO	Assessment Object	Assessment Techniques	Score		
Study/exam achievements:	1	1-3	Subject specific competence: a. Individual assignments b. Mid Exam	Written Written test	10% 40%		
	2	4 – 10	a. Individual assignments b. Final Exam	Written Written test	10% 40%		
	Total		100%				
Forms of media:	Board, LCD Projector, Laptop/Computer, LMS						
Literature:	 Suhandi dan Y. R. Tayubi (2017) Fisika Piranti Semikonduktor, Belum diterbitkan. S. M. Sze, and Ming-Kwei Lee, (2012). Semiconductor Devices: Physics and Technology, John Wiley & Sons. J. Singh, (2019) Semiconductor Optoelectronics; Physics & Technology, McGraw-Hill Inc. Kwok K. Ng, (2002). Complete Guide to Semiconductor Devices, 2nd Edition. Wiley-IEEE Press. 						

PLO and CLO mapping

	PLO1	PLO2	PLO3	PLO4	PLO5	PLO6	PLO7	PLO8	PLO9	PLO10	PLO11	PLO12
CLO1		1										
CLO2		V										
CLO3		1										
CLO4		V										
CLO5												
CLO6												
CLO7												
CLO8		V										
CLO9		√										
CLO1 0		V										